

DECLARATION FOR PATENT APPLICATION

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below adjacent to my name.

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of subject matter (process, machine, manufacture, or composition of matter, or an improvement thereof) which is claimed and for which a patent is sought by way of the application entitled

MOSFET MODELING FOR IC DESIGN ACCURATE FOR HIGH FREQUENCIES

- which (check) is attached hereto.
 and is amended by the Preliminary Amendment attached hereto.
 was filed on September 14, 2000 as Application Serial No. 09/661,328
 and was amended on (if applicable).

I hereby state that I have reviewed and understand the contents of the above identified specification, including the claims, as amended by any amendment referred to above.

I acknowledge the duty to disclose information, which is material to patentability as defined in Title 37, Code of Federal Regulations, § 1.56.

I declare that all statements made herein of my own knowledge are true, all statements made herein on information and belief are believed to be true, and all statements made herein are made with the knowledge that whoever, in any matter within the jurisdiction of the Patent and Trademark Office, knowingly and willfully falsifies, conceals, or covers up by any trick, scheme, or device a material fact, or makes any false, fictitious or fraudulent statements or representations, or makes or uses any false writing or document knowing the same to contain any false, fictitious or fraudulent statement or entry, shall be subject to the penalties including fine or imprisonment or both as set forth under 18 U.S.C. 1001, and that violations of this paragraph may jeopardize the validity of the application or this document, or the validity or enforceability of any patent, trademark registration, or certificate resulting therefrom.

Full name of first joint inventor: Xisheng Zhang
Inventor's Signature: Xisheng Zhang Date: 3/26/01
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Full name of second joint inventor: Hancheng Liang
Inventor's Signature: Hancheng Liang Date: 3-12-2001
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Full name of second joint inventor: Zhihong Liu
Inventor's Signature: Zhihong Liu Date: 3/26/2001
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Full name of second joint inventor: Jianhe Guo
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